



WBA0010A

10 ~ 1000 MHz LOW NOISE AMPLIFIER

REV A
August 2013

Key Features



- 10 ~ 1000 MHz
- **0.65 ~ 1.5 dB Noise Figure**
- 21.0 dBm Output P_{1dB}
- 35.0 dB Gain
- **+/- 0.20 dB Gain Flatness**
- 1.5:1 VSWR
- Single power supply
- >34 years MTBF
- RoHS compliant
- Meet MIL-STD-202

Product Description

WBA0010A integrates WanTcom proprietary power amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and exceptional gain flatness performances together. With single DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard SMA connectorized WP-11 gold plated housing.



Applications

- Radio Infrastructures
- SW Communications
- Cellular Base Stations
- FM
- Measurement
- Fixed Wireless



Specifications

Summary of the electrical specifications WBA0010A at room temperature

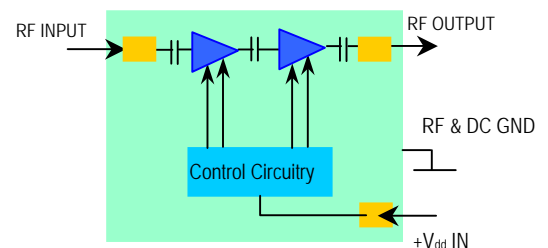
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	10 – 1000 MHz	33	35	37	dB
2	Gain Variation	ΔG	10 – 1000 MHz		+/- 0.20	+/-0.5	dB
3	Noise Figure	NF	20 – 1000 MHz		0.65	1.2	dB
4	Input VSWR	SWR ₁	20 – 1000 MHz		1.35:1	1.5:1	Ratio
5	Output VSWR	SWR ₂	10 – 1000 MHz		1.35:1	1.5:1	Ratio
6	Reverse Isolation	S ₁₂	10 – 1000 MHz		50		dB
7	Output Power 1dB compression Point	P _{1dB}	10 – 1000 MHz	19	21		dBm
8	Output Third Interception Point	OIP ₃	10 – 1000 MHz, 1 MHz Separation, 10 dBm each tone	34	36		dBm
9	Current Consumption	I _{dd}	V _{dd}		150		mA
10	Power Supply Voltage	V _{dd}	WBA0010A	+4.7	+5.0	+5.3	V
11	Thermal Resistance	R _{th,c}	Junction to case			40	°C/W
12	Operating Temperature	T _o		-40		+85	°C
13	Maximum Average RF Input Power	P _{IN, MAX}	DC – 6 GHz			10	dBm
14	Stability Factor	k	DC – 26.5 GHz, unconditional stable	1.0			--

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	6
Drain Current	mA	180
Total Power Dissipation	W	1.2
RF Input Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85
Thermal Resistance	°C/W	40

Operation of this device above any one of these parameters may cause permanent damage.

Functional Block Diagram



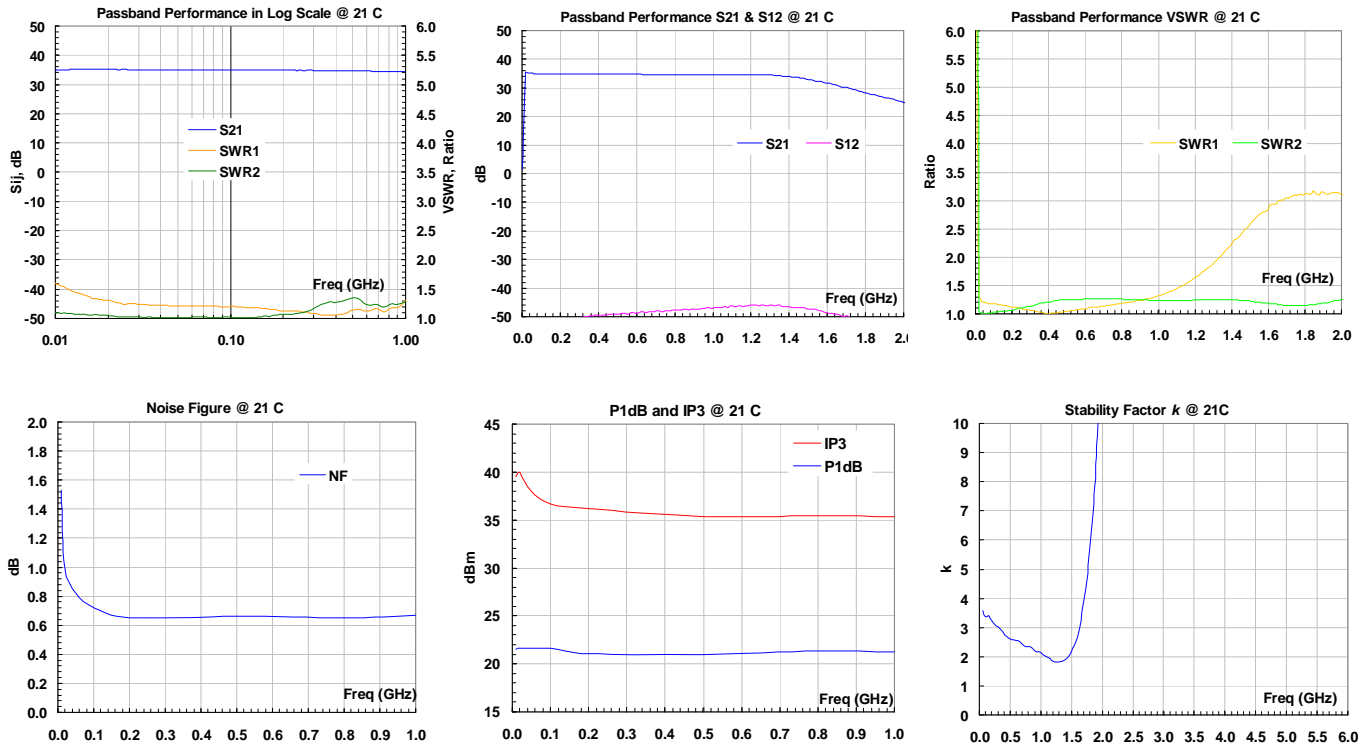
Ordering Information

Model Number	WBA0010A
--------------	----------

Specifications and information are subject to change without notice.

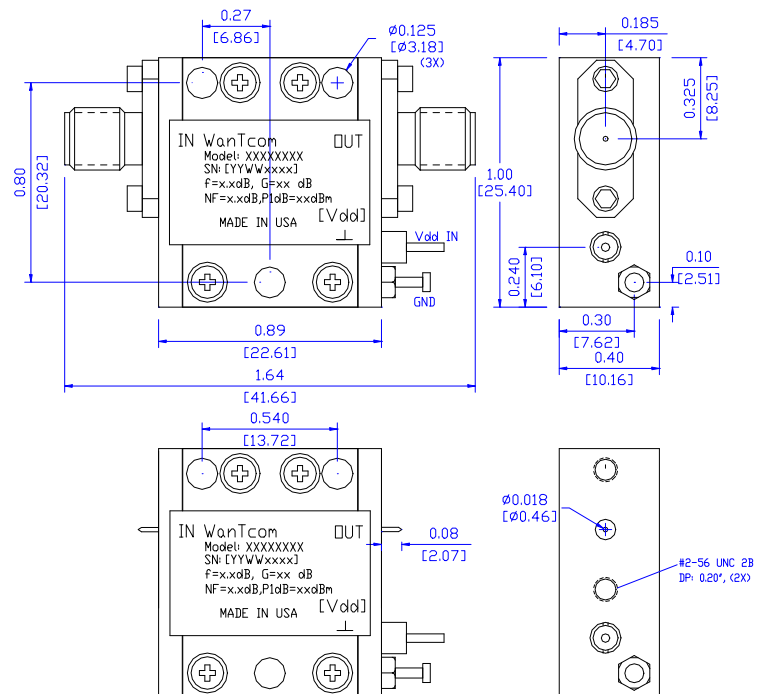


Typical Data:



Outline, WP-11 Housing

UNITS: INCH
[mm]
BODY: Brass
Finish: Gold Plating
RF Connector: SMA F Gold Field Replaceable
V_{dd} PWR: Feed through



Specifications and information are subject to change without notice.



Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with 5 ~ 6 inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.
